



QSFP28 100G CWDM4 2km Transceiver



Features

- Hot-pluggable QSFP28 form factor
- 4 x CWDM uncooled DFB laser
- (1271/1291/1311/1331 nm)
- PIN photo detector
- 0°C to 70°C case operating temperature range
- 2km transmission with SMF
- 3.3 V power supply
- Contain clock data recovery (CDR)
- Power consumption < 3.5 W
- Compliant with QSFP+ MSA SFF-8665
- Compliant with IEEE 802.3bm/100G-CWDM4 MSA specification
- Digital diagnostic functions (Via I²C)
- RoHS compliant
- Compliant with UL & TUV



Applications

• 100 Gigabit Ethernet, Dual LC, CWDM4





Part Numbers

Part Number	Form Factor	Data Rate	Media	Distance	Wavelength	TX Power	Voltage	Coupling	DDM	Temp
STA-100G-CWDM4	QSFP28 Dual LC	100G	SMF	2km	1271 nm 1291 nm 1311 nm 1331 nm	-6.5 ~ 2.5	3.3 V	AC/AC	Υ	0 ~ +70 C

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Min	Max	Unit
Storage temperature	T _s		-40	+85	°C
Supply relative humidity	RH	Non condensing	0	85	%
Supply voltage	V _{cc}		0	3.6	V

Recommended Operating Conditions

Parameter	Symbol	Conditions	Min	Typical	Max	Unit
Case operating temperature	T _c		0		70	°C
Supply voltage	V _{cc}		3.13	3.3	3.47	V
Supply voltage	l _{cc}				1000	mA
Data rate	DR			100		Gbps
Distance			0.002		2	km

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Unit
Transmitter						
Differential input impedance	R_{DI}			100		Ohm
High speed differential input voltage (CML)	$V_{\text{CML_DI}}$	AC-coupled, peak to peak	0.2		1.0	V
Low speed input voltage - low (LVCOMS)	$V_{_{LVCMOS_IL}}$				Vcc*0.2	V
Low speed input voltage - high (LVCOMS)	$V_{\scriptscriptstyle LVCMOS_IH}$		Vcc*0.75		3.465	V
Receiver						
Differential output impedance	R_{DO}			100		Ohm
High speed differential output voltage (CML)	$V_{\text{CML_DO}}$	AC-coupled, peak to peak	0.3		8.0	V
Low speed output voltage - low (LVCOMS)	$V_{\scriptscriptstyle LVCMOS_OL}$		0		0.4	V
Low speed output voltage -high (LVCOMS)	$V_{\scriptscriptstyle LVCMOS_OH}$		Vcc-0.5		Vcc+0.3	V





Optical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Unit
Transmitter						
Lane wavelengths (range)	λο		1264.5	1271	1277.5	nm
			1284.5	1291	1297.5	nm
			1304.5	1311	1317.5	nm
			1324.5	1331	1337.5	nm
Side mode suppression ratio	SMSR		30			dB
Total average launch power	Ptot				8.5	dBm
Average launch power, each lane	Po		-6.5		2.5	dBm
OMA, each lane	OMA	CW,ER>3.5dB	-4		2.5	dBm
Difference in launch power between any two lanes (OMA)					5	dB
TDP, each lane	TDP				3.0	dB
Average launch power of OFF transmitter, each lane	Poff				-30	dBm
Extinction ratio	ER		3.5			dB
Eye mask definition {X1, X2, X3, Y1, Y2, Y3}			{0.31, 0.40	, 0.45, 0.34,	0.38, 0.4}	
Receiver						
Center wavelength - lane 0	λ_{CO}		1264.5		1277.5	nm
Center wavelength - lane 1	$\boldsymbol{\lambda}_{C1}$		1284.5		1297.5	nm
Center wavelength - lane 2	$\boldsymbol{\lambda}_{C2}$		1304.5		1317.5	nm
Center wavelength - lane 3	λ_{C3}		1324.5		1337.5	nm
Damage threshold			3.5			dBm
Receiver power (OMA), each lane					2.5	dBm
Receiver reflectance					-26	dB
Difference in receiver power between any two lanes (OMA) (max)					5.5	dB
Average receive power, each lane			-11.5		2.5	dBm
Receiver sensitivity (OMA), each lane	Rsens	At 5E-5 BER			-10.0	dBm
Stressed receiver sensitivity (OMA), each lane	SRS	At 5E-5 BER				
Conditions of stressed receiver sensitivity test:						
Vertical eye closure penalty, each lane	VECP			1.9		dB
Stressed eye J2 jitter, each lane	J2			0.33		UI
Stressed eye J4 jitter, each lane	J4			0.48		UI
SRS eye mask definition {X1, X2, X3,Y1, Y2, Y3}			{O	39 0 50 0 5	0, 0.39, 0.39,	

- 1. FEC reqiurements as defined by the 100G CWDM4 MSA Technical Specification Rev 1.1
- 2. The Receiver sensitivity (OMA), each lane (Max) at 5E-5 BER is a normative specification
 3. The conditions of the stressed receiver sensitivity test section are NOT characteristics of the reciever

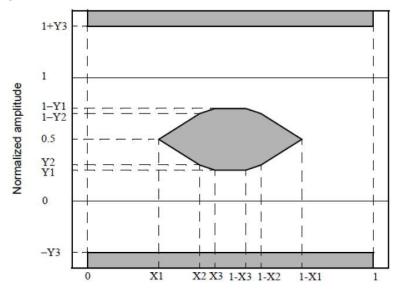




Product Label



Eye Mask Definition



X1	0.31	Y1	0.34
X2	0.40	Y2	0.38
Х3	0.45	Y3	0.4

2

3

4

5

6

8

10

11

12

13

15 16 17

18

19

Normalized time (Unit Interval)

GND

TX2n

TX2p

GND

TX4n

TX4p

GND

Modse L

ResetL

VccRx

SCL

SDA

GND

RX3p

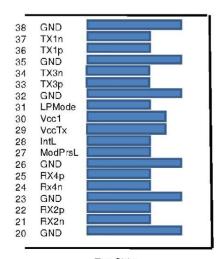
Rx3n

GND RX1p

RX1n

GND

Pin Description



Module Card Edge

Bottom Side Viewed From Bottom







Pin Function Definitions

Pin	Logic	Symbol	Description	Notes
1		GND	Ground	1
2	CML-I	Tx2n	Transmitter inverted data input	
3	CML-I	Tx2p	Transmitter non-inverted data input	
4		GND	Ground	1
5	CML-I	Tx4n	Transmitter inverted data input	
6	CML-I	Tx4p	Transmitter non-inverted data input	
7		GND	Ground	1
8	LVTTL-I	ModSelL	Module select	
9	LVTTL-I	ResetL	Module reset	
10		Vcc Rx	+3.3 V power supply receiver	2
11	LVCMOS I / O	SCL	2-wire serial interface clock	
12	LVCMOS I / O	SDA	2-wire serial interface data	
13		GND	Ground	1
14	CML-O	Rx3p	Receiver non-inverted data output	
15	CML-O	Rx3n	Receiver inverted data output	
16		GND	Ground	1
17	CML-O	Rx1p	Receiver non-inverted data output	
18	CML-O	Rx1n	Receiver inverted data output	
19		GND	Ground	1
20		GND	Ground	1
21	CML-O	Rx2n	Receiver inverted data output	
22	CML-O	Rx2p	Receiver non-inverted data output	
23		GND	Ground	1
24	CML-O	Rx4n	Receiver inverted data output	
25	CML-O	Rx4p	Receiver non-inverted data output	
26		GND	Ground	1
27	LVTTL-O	ModPrsL	Module present	
28	LVTTL-O	IntL	Interrupt	
29		Vcc Tx	+3.3 V power supply transmitter	2
30		Vcc1	+3.3 V power supply	2
31	LVTTL-I	LPMode	Low power mode	
32		GND	Ground	1
33	CML-I	Тх3р	Transmitter non-inverted data input	
34	CML-I	Tx3n	Transmitter inverted data input	
35		GND	Ground	1
36	CML-I	Tx1p	Transmitter non-inverted data input	
37	CML-I	Tx1n	Transmitter inverted data input	
38		GND	Ground	1

Note 1: GND is the symbol for signal and supply (power) common for the QSFP+ module. All are common within the QSFP+ module and all module voltages are referenced to this potential unless otherwise noted. Connect these directly to the host board signal-common ground plane.

Note 2 : Vcc Rx, Vcc1 and Vcc Tx are the receiver and transmitter power supplies and shall be applied concurrently.



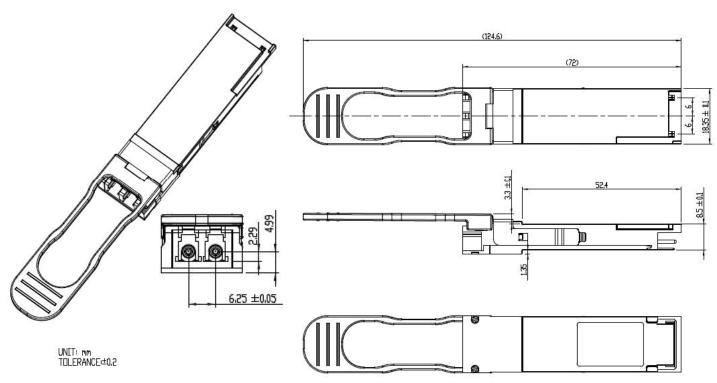


Ordering Information



Part Drawings

Mechanical Design Diagram (mm)







Regulatory Compliance

Standard
FCC art 15 Class B CE EN55032+EN55035 VCCI CISPR32
Contact discharge EN61000-4-2 criterion B
Air discharge EN61000-4-2 criterion B
ANSI/ESDA/JEDEC JS-001
2011/65/EU
FDA 21CFR 1040.10 and 1040.11
UL and TUV

Laser Safety Information

All versions of this laser are Class 1 laser products per IEC/EN 60825-1. Users should observe safety precautions such as those recommended by ANSI³ Z136.1, ANSI Z36.2 and IEC 60825-1.

This product conforms to FDA (CDRH) 21 CFR 1040.10 and 1040.11 except for deviations of laser safety class designation pursuant to 'Laser Notice No.50'

Product labeling: Class 1 Laser Product Compliance with 21 CFR 1040.10 and 1040.11

If labeling is not affixed to the module due to size constraints; then rather, labeling is placed on the outside of the shipping box. This product is not shipped with a power supply.

Caution: use of controls or adjustments or performance of procedures other than those specified herein may result in hazardous radiation exposure.

Certifications

UL: 62368-1

TUV: EN62368-1, EN 60825-1, EN 60825-2 Documentation is available upon request.

- (1) IEC is a registered trademark of the International Electrotechnical Commission
- (2) Within Europe the IEC standard has been adopted as a European Normative standard known as EN 60825, and each European country will have its own version of this standard, for example, the British Standards version known as BS EN 60825. There can be small differences between the different countries versions of EN 60825, and these are in part caused by the process of translating the standard into the native language of that country.
- (3) ANSI is a registered trademark of the American National Standards Institute

